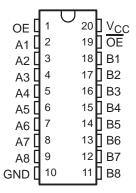
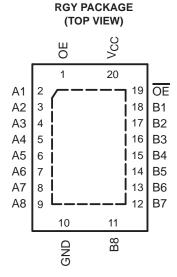
- **Undershoot Protection for Off-Isolation on** A and B Ports Up To -2 V
- **Bidirectional Data Flow, With Near-Zero Propagation Delay**
- Low ON-State Resistance (ron) Characteristics ( $r_{on} = 3 \Omega$  Typical)
- **Low Input/Output Capacitance Minimizes Loading and Signal Distortion**  $(C_{io(OFF)} = 5.5 pF Typical)$
- **Data and Control Inputs Provide Undershoot Clamp Diodes**
- **Low Power Consumption**  $(I_{CC} = 3 \mu A Max)$
- V<sub>CC</sub> Operating Range From 4 V to 5.5 V
- Data I/Os Support 0 to 5-V Signaling Levels (0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, 5-V)

DB, DBQ, DGV, DW, OR PW PACKAGE (TOP VIEW)



- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Performance Tested Per JESD 22** 
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- **Supports Both Digital and Analog** Applications: USB Interface, Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating



#### description/ordering information

The SN74CBT3345C is a high-speed TTL-compatible FET bus switch with low ON-state resistance (ron), allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBT3345C provides protection for undershoot up to -2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBT3345C is organized as an 8-bit bus switch with two output-enable (OE,  $\overline{OE}$ ) inputs. When OE is high or  $\overline{\sf OE}$  is low, the bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When OE is low and  $\overline{\rm OE}$  is high, the bus switch is OFF and the high-impedance state exists between the A and B ports.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



## description/ordering information (continued)

This device is fully specified for partial-power-down applications using  $I_{\mbox{off}}$ . The  $I_{\mbox{off}}$  feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to  $V_{CC}$  through a pullup resistor, and OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking/current-sourcing capability of the driver.

#### **ORDERING INFORMATION**

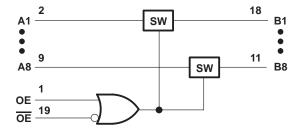
TA	PACKAGI	ΕŢ	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Tape and reel	SN74CBT3345CRGYR	CU345C
	2010 514	Tube	SN74CBT3345CDW	00700450
	SOIC - DW	Tape and reel	SN74CBT3345CDWR	CBT3345C
	CCOD DD	Tube	SN74CBT3345CDB	CHAFC
-40°C to 85°C	SSOP – DB	Tape and reel	SN74CBT3345CDBR	CU345C
	SSOP (QSOP) – DBQ	Tape and reel	SN74CBT3345CDBQR	CBT3345C
	TOOOD DW	Tube	SN74CBT3345CPW	0110450
	TSSOP – PW	Tape and reel	SN74CBT3345CPWR	CU345C
	TVSOP - DGV	Tape and reel	SN74CBT3345CDGVR	CU345C

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

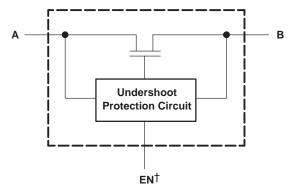
#### **FUNCTION TABLE**

INP	JTS	INPUT/OUTPUT	FUNCTION			
OE	OE	Α	FUNCTION			
Н	Х	В	A port = B port			
Х	L	В	A port = B port			
L	Н	Z	Disconnect			

#### logic diagram (positive logic)



## simplified schematic, each FET switch (SW)



†EN is the internal enable signal applied to the switch.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V <sub>CC</sub>	
Control input voltage range, V <sub>IN</sub> (see Notes 1 and 2)	–0.5 V to 7 V
Switch I/O voltage range, V <sub>I/O</sub> (see Notes 1, 2, and 3)	-0.5  V to 7 V
Control input clamp current, I <sub>IK</sub> (V <sub>IN</sub> < 0)	–50 mA
I/O port clamp current, $I_{I/OK}$ ( $V_{I/O}$ < 0)	–50 mA
ON-state switch current, I <sub>I/O</sub> (see Note 4)	
Continuous current through V <sub>CC</sub> or GND terminals	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 5): DB package	
(see Note 5): DBQ package	68°C/W
(see Note 5): DGV package	92°C/W
(see Note 5): DW package	58°C/W
(see Note 5): PW package	83°C/W
(see Note 6): RGY package	37°C/W
Storage temperature range, T <sub>stg</sub> –	65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to ground unless otherwise specified.

- 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 3. V<sub>I</sub> and V<sub>O</sub> are used to denote specific conditions for V<sub>I/O</sub>.
- 4. II and IO are used to denote specific conditions for II/O.
- 5. The package thermal impedance is calculated in accordance with JESD 51-7.
- 6. The package thermal impedance is calculated in accordance with JESD 51-5.

## recommended operating conditions (see Note 7)

		MIN	MAX	UNIT
Vcc	Supply voltage	4	5.5	V
VIH	High-level control input voltage	2	5.5	V
VIL	Low-level control input voltage	0	8.0	V
V <sub>I/O</sub>	Data input/output voltage	0	5.5	V
TA	Operating free-air temperature	-40	85	°C

NOTE 7: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAF	RAMETER		TEST CONDITIO	NS	MIN	TYP†	MAX	UNIT
VIK	Control inputs	$V_{CC} = 4.5 \text{ V},$	$I_{IN} = -18 \text{ mA}$				-1.8	V
VIKU	Data inputs	V <sub>CC</sub> = 5 V,	$0 \text{ mA} > I_{I} \ge -50 \text{ mA},$ $V_{IN} = V_{CC} \text{ or GND},$	Switch OFF			-2	V
I <sub>IN</sub>	Control inputs	$V_{CC} = 5.5 \text{ V},$	$V_{IN} = V_{CC}$ or GND				±1	μΑ
I <sub>OZ</sub> ‡		V <sub>CC</sub> = 5.5 V,	$V_O = 0 \text{ to } 5.5 \text{ V},$ $V_I = 0,$	Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND			±10	μА
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_0 = 0 \text{ to } 5.5 \text{ V},$	V <sub>I</sub> = 0			10	μΑ
ICC		V <sub>CC</sub> = 5.5 V,	$I_{I/O} = 0,$ $V_{IN} = V_{CC} \text{ or GND},$	ND, Switch ON or OFF			3	μΑ
∆lcc§	Control inputs	$V_{CC} = 5.5 \text{ V},$	One input at 3.4 V,	Other inputs at V <sub>CC</sub> or GND			2.5	mA
C <sub>in</sub>	Control inputs	$V_{IN} = 3 V \text{ or } 0$				4		pF
C <sub>io(OFF)</sub>		$V_{I/O} = 3 \text{ V or } 0,$	Switch OFF,	$V_{IN} = V_{CC}$ or GND		5.5		pF
C <sub>io(ON)</sub>		$V_{I/O} = 3 \text{ V or } 0,$	Switch ON,	$V_{IN} = V_{CC}$ or GND		14		pF
		$V_{CC} = 4 \text{ V},$ TYP at $V_{CC} = 4 \text{ V}$	V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA		8	12	
r <sub>on</sub> ¶				I <sub>O</sub> = 64 mA		3	6	Ω
		V <sub>CC</sub> = 4.5 V	V <sub>I</sub> = 0	I <sub>O</sub> = 30 mA	3		6	]
			V <sub>I</sub> = 2.4 V,	$I_{O} = -15 \text{ mA}$		5	10	

## switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 4 V	± 0.5	UNIT	
	(INPOT)	(001701)	MIN MAX	MIN	MAX	
t <sub>pd</sub> #	A or B	B or A	0.24		0.15	ns
t <sub>en</sub>	OE or OE	A or B	5.3	1.5	4.9	ns
t <sub>dis</sub>	OE or OE	A or B	5.8	1.5	5.7	ns

<sup>#</sup>The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

 $V_{IN}$  and  $I_{IN}$  refer to control inputs.  $V_{I}$ ,  $V_{O}$ ,  $I_{I}$ , and  $I_{O}$  refer to data pins. † All typical values are at  $V_{CC}$  = 5 V (unless otherwise noted),  $T_{A}$  = 25°C.

For I/O ports, the parameter IOZ includes the input leakage current.

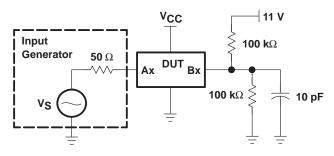
<sup>§</sup> This is the increase in supply current for each input that is at the specified voltage level, rather than V<sub>CC</sub> or GND.

<sup>¶</sup>Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

## undershoot characteristics (see Figures 1 and 2)

ĺ	PARAMETER		TEST CONDI	MIN	TYP†	MAX	UNIT	
ſ	Voutu	$V_{CC} = 5.5 \text{ V},$	Switch OFF,	V <sub>IN</sub> = V <sub>CC</sub> or GND	2	V <sub>OH</sub> -0.3		V

 $<sup>\</sup>dagger$  All typical values are at V<sub>CC</sub> = 5 V (unless otherwise noted), T<sub>A</sub> = 25°C.





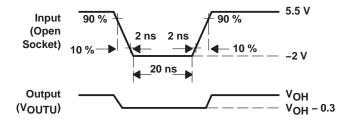
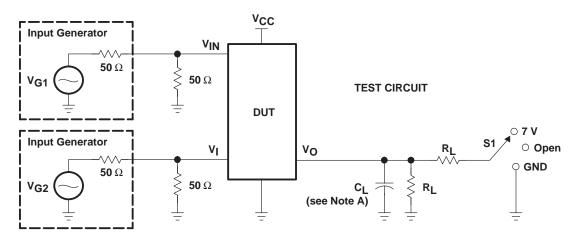
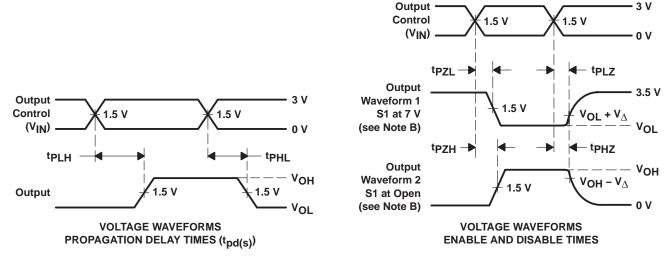


Figure 2. Transient Input Voltage (V<sub>I</sub>) and Output Voltage (V<sub>OUTU</sub>) Waveforms (Switch OFF)

#### PARAMETER MEASUREMENT INFORMATION



TEST	VCC	V <sub>CC</sub> S1 R <sub>L</sub>		VI	CL	$v_{\!\scriptscriptstyle\Delta}$
<sup>t</sup> pd(s)	$\begin{array}{c} \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{4 V} \end{array}$	Open Open	<b>500</b> Ω <b>500</b> Ω	V <sub>CC</sub> or GND V <sub>CC</sub> or GND	50 pF 50 pF	
tPLZ/tPZL	5 V ± 0.5 V 4 V	7 V 7 V	<b>500</b> Ω <b>500</b> Ω	GND GND	50 pF 50 pF	0.3 V 0.3 V
tPHZ/tPZH	5 V ± 0.5 V 4 V	Open Open	<b>500</b> Ω <b>500</b> Ω	V <sub>CC</sub>	50 pF 50 pF	0.3 V 0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Test Circuit and Voltage Waveforms









## **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74CBT3345CDBQR	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74CBT3345CDBQRE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74CBT3345CDBQRG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74CBT3345CDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDGVRE4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDGVRG4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CPWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CPWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBT3345CRGYR	ACTIVE	QFN	RGY	20	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74CBT3345CRGYRG4	ACTIVE	QFN	RGY	20	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs. **LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.



#### PACKAGE OPTION ADDENDUM

28-May-2007

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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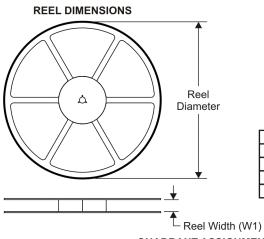
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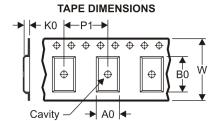




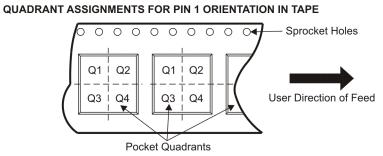
ti.com 11-Mar-2008

#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CBT3345CDBQR	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74CBT3345CDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74CBT3345CDGVR	TVSOP	DGV	20	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
SN74CBT3345CDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74CBT3345CPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74CBT3345CRGYR	QFN	RGY	20	1000	180.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1





\*All dimensions are nominal

All difficultions are norminal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CBT3345CDBQR	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
SN74CBT3345CDBR	SSOP	DB	20	2000	346.0	346.0	33.0
SN74CBT3345CDGVR	TVSOP	DGV	20	2000	346.0	346.0	29.0
SN74CBT3345CDWR	SOIC	DW	20	2000	346.0	346.0	41.0
SN74CBT3345CPWR	TSSOP	PW	20	2000	346.0	346.0	33.0
SN74CBT3345CRGYR	QFN	RGY	20	1000	190.5	212.7	31.8

## DB (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

#### **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

## PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

## DGV (R-PDSO-G\*\*)

#### 24 PINS SHOWN

#### **PLASTIC SMALL-OUTLINE**

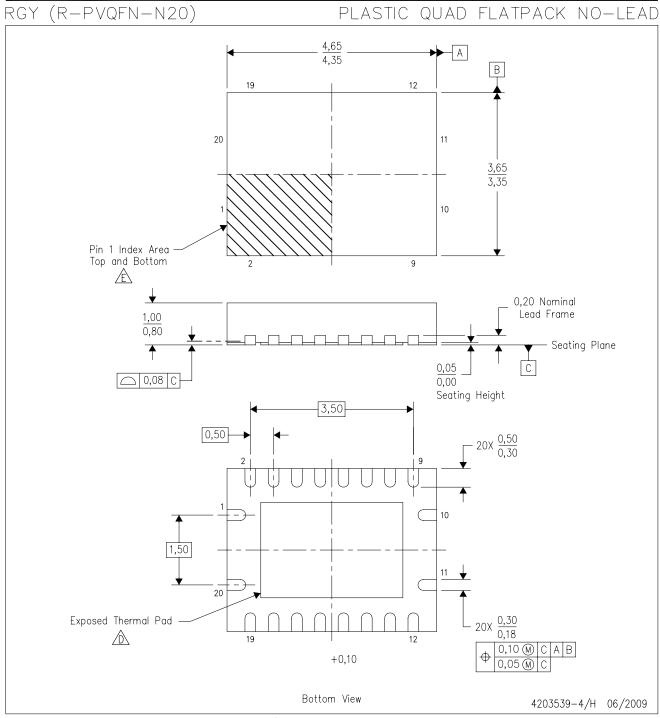


NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.

  See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BC.



#### THERMAL PAD MECHANICAL DATA



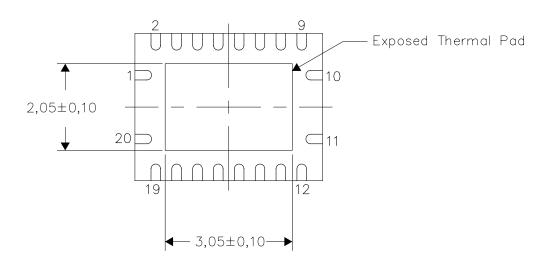
RGY (R-PVQFN-N20)

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

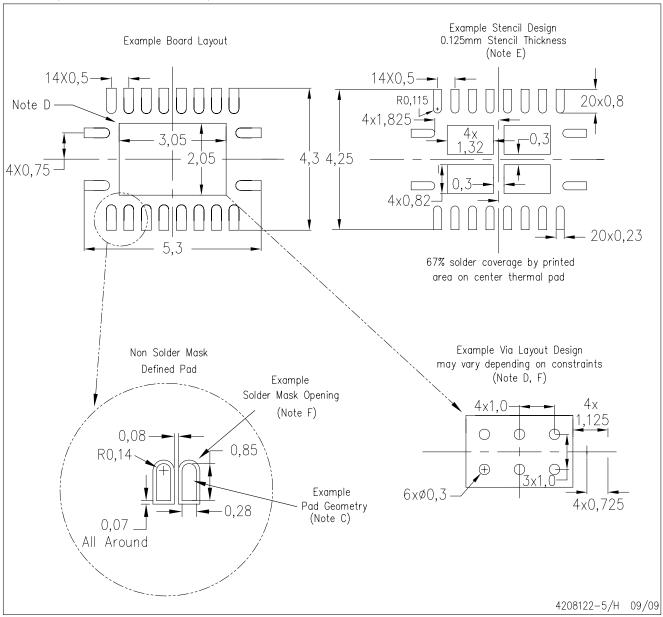


Bottom View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

## RGY (R-PVQFN-N20)

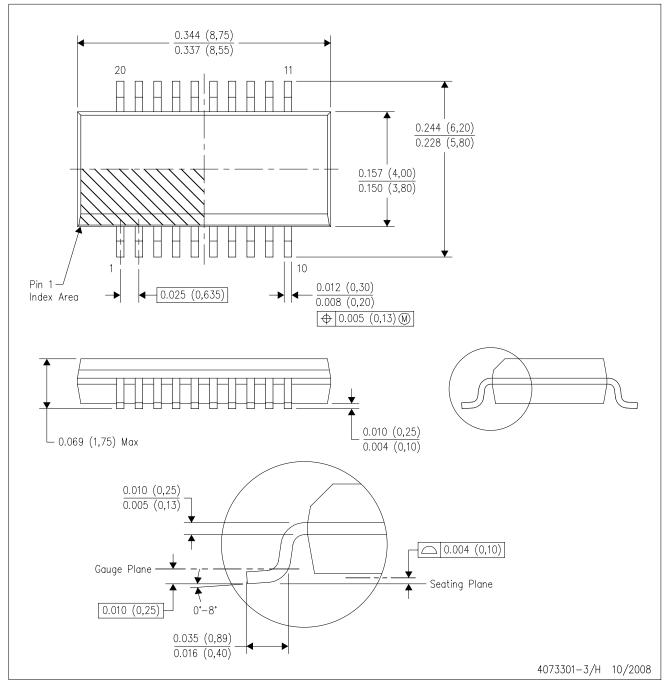


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



DBQ (R-PDSO-G20)

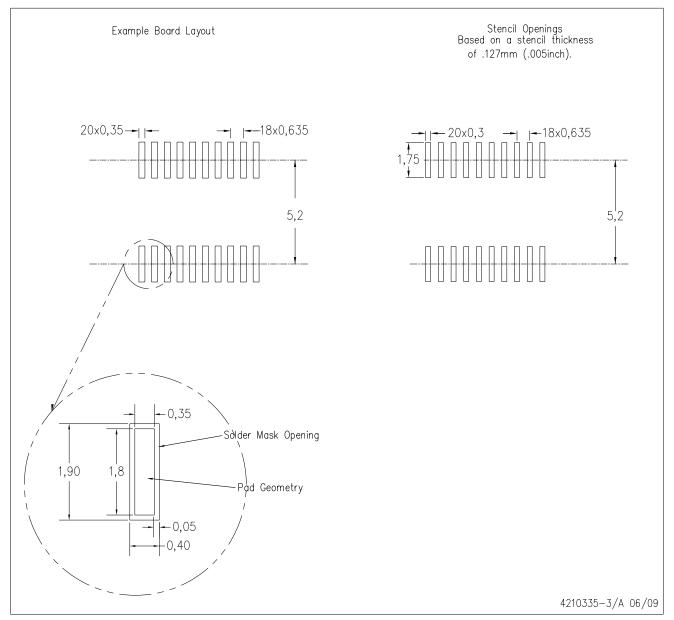
## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.



# DBQ (R-PDSO-G20)



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



# DW (R-PDSO-G20)

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



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